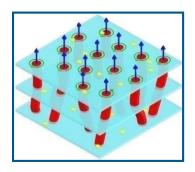




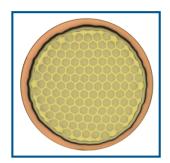
Superconductivity and its applications

Lecture 6



Carmine SENATORE



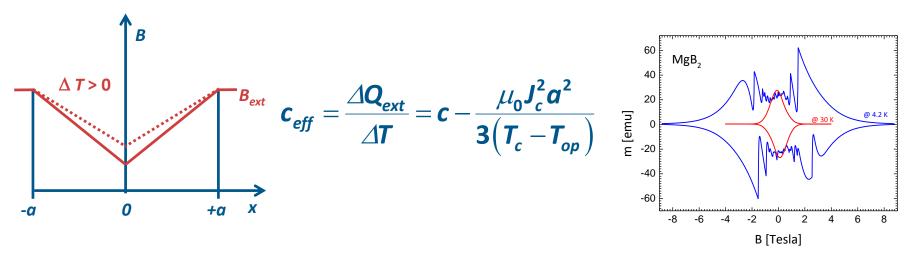


Previously, in lecture 5

- 1) In a wire the subdivision of the superconductor in fine filaments is required
 - to reduce hysteretic losses

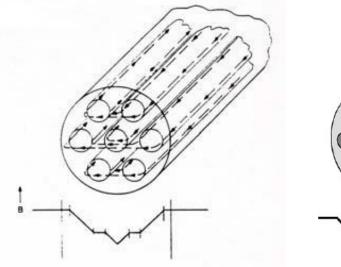


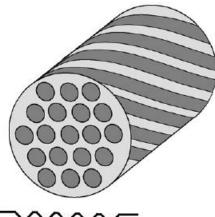
• to reduce thermal instabilities



Previously, in lecture 5

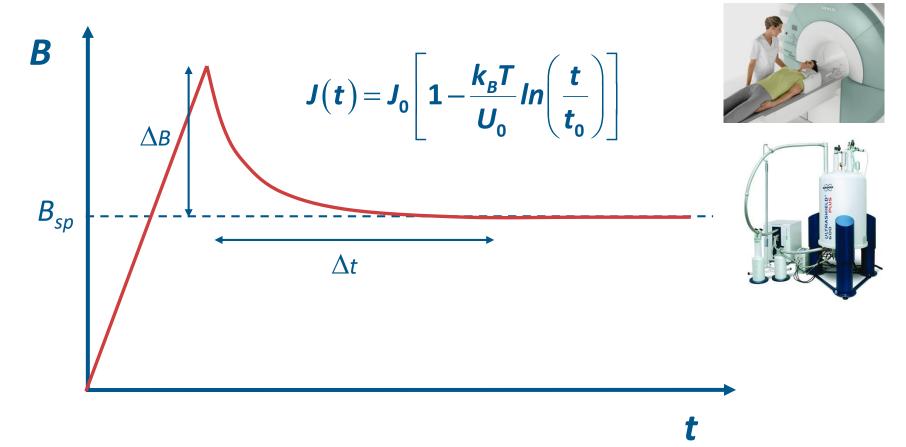
2) When the matrix resistivity is too low, wires have to be twisted to avoid inductive coupling among the filaments (and thus losses)



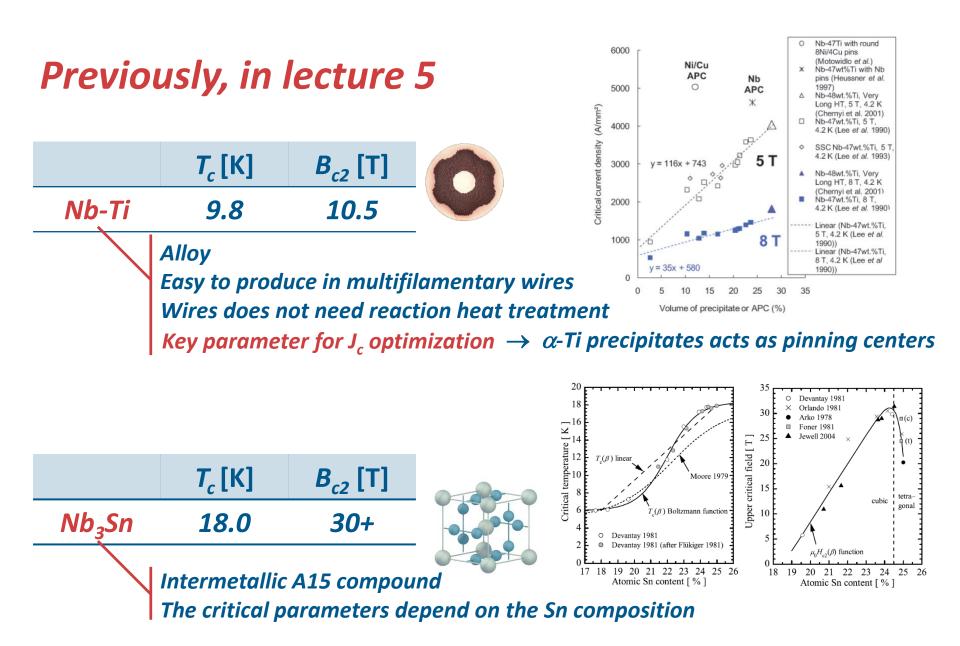


 $2\rho_n J_c a$

Previously, in lecture 5 Flux creep and Persistent mode operation in a magnet



At the operation, the drift of the field is 10 ppb/hour The field is reduced by half in ~6'000 years !!



Martensitic transformation

Structural phase transformation from cubic to tetragonal at low temperatures

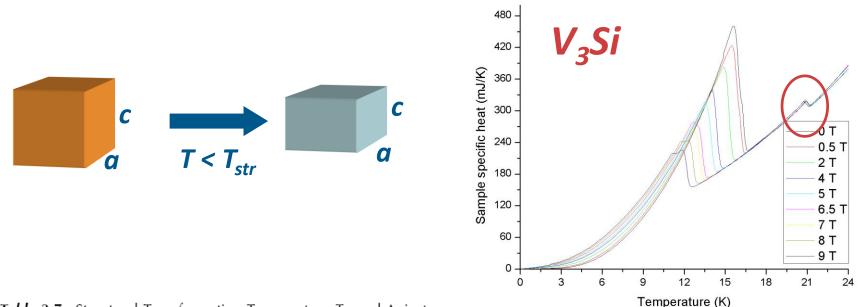


Table 3.7	Structural Transformation Temperature T _{str} and Anisotr	
Low-Temp	erature Tetragonal Phase of Several A15 type Superconductors	

Compound	$T_{ m str}$ (K)	Т _с (К)	Anisotropy $(c-a)/a$	Reference
V ₃ Si	21	17	0.0024	Batterman and Barrett (1964)
Nb ₃ Sn	43	18	-0.0061	Mailfert et al. (1967)
V ₃ Ga	> 50	14.5	_	Nembach et al. (1970)
Nb ₃ Al	80	17.9	_	Kodess (1973, 1982)
Nb ₃ (Al _{0.75} Ge _{0.25})	105	18.5	-0.003	Kodess (1973, 1982)
$Nb_{3.1}(Al_{0.7}Ge_{0.3})$	130	17.4	—	Kodess (1973, 1982)

How to rise H_{c2} – Let's play it dirty

For a clean, ordered superconductor

$$H_{c2} = \frac{\Phi_0}{2\pi\xi^2}$$

Disorder reduces the electron mean free path $\,\ell$, which in turn leads to decrease of ξ

$$\frac{\mathbf{1}}{\xi(\ell)} = \frac{\mathbf{1}}{\xi(\infty)} + \frac{\mathbf{1}}{\ell}$$

An useful expression of H_{c2} in the dirty limit

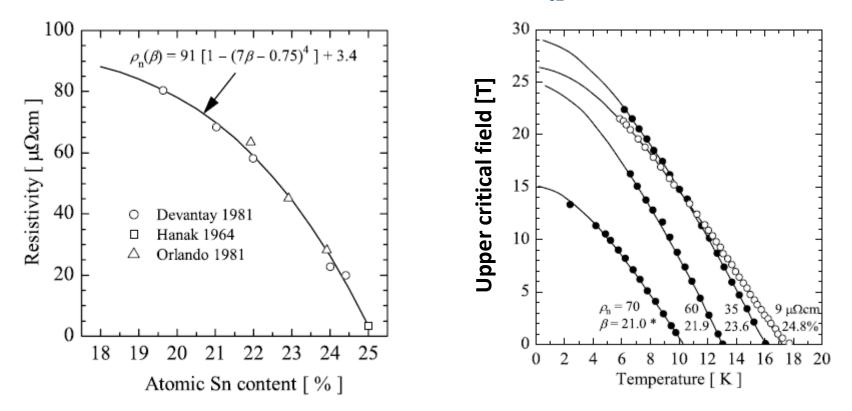
$$\boldsymbol{H_{c2}}(\boldsymbol{T}=\boldsymbol{0}) \cong \frac{\boldsymbol{k_{B}}\boldsymbol{e}}{\mu_{0}} \boldsymbol{N}(\boldsymbol{E_{F}}) \boldsymbol{\rho_{n}} \boldsymbol{T_{c}} \propto \gamma \boldsymbol{\rho_{n}} \boldsymbol{T_{c}}$$

How to rise H_{c2} in Nb₃Sn

$H_{c2} \propto \gamma \rho_n T_c$

Resistivity vs. Sn at.%

 H_{c2} vs. T at various Sn at.%



Reducing Sn content rises ρ_n , but reduces T_c . Other ideas ?

Graphs from A. Godeke, PhD Thesis, UTwente

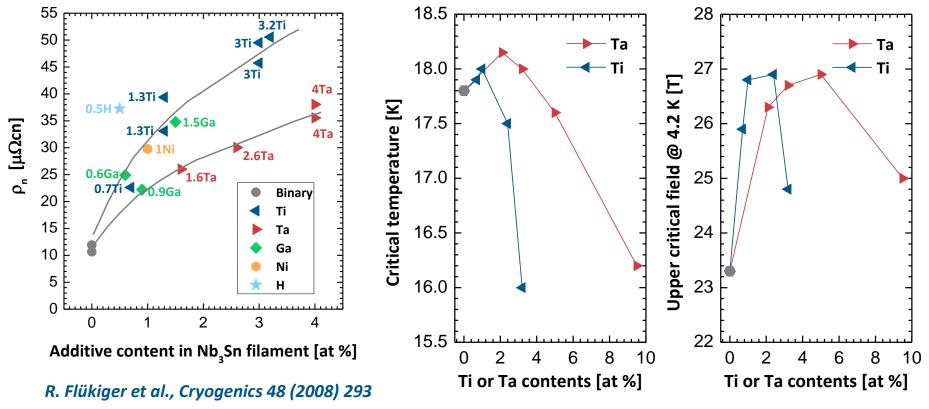
Alloying (doping) Nb₃Sn to rise $H_{c2} = H_{c2} \propto \gamma \rho_n T_c$

The additions of Ta and Ti are particularly beneficial

 $H_{c2}(4.2 K)$

 $H_{c2}(0 K$

= 0.89



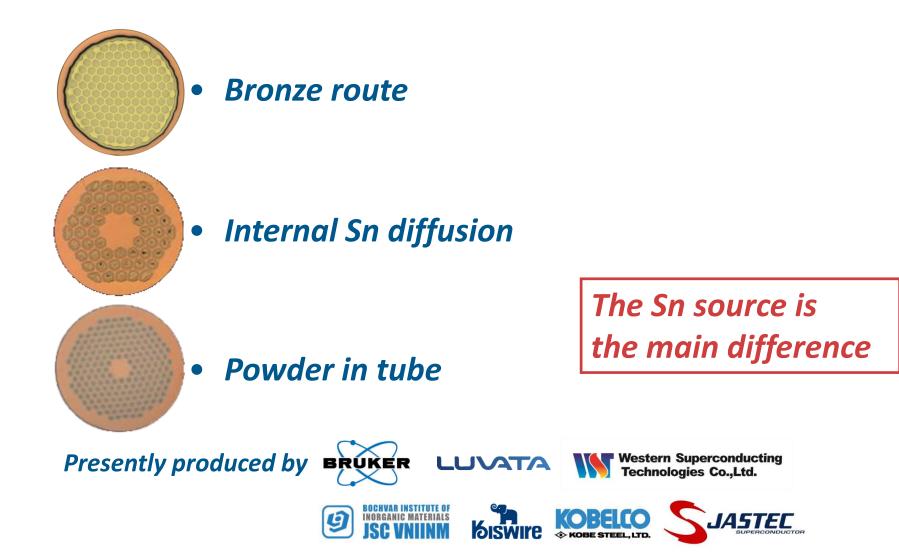
Ti substitutes Nb

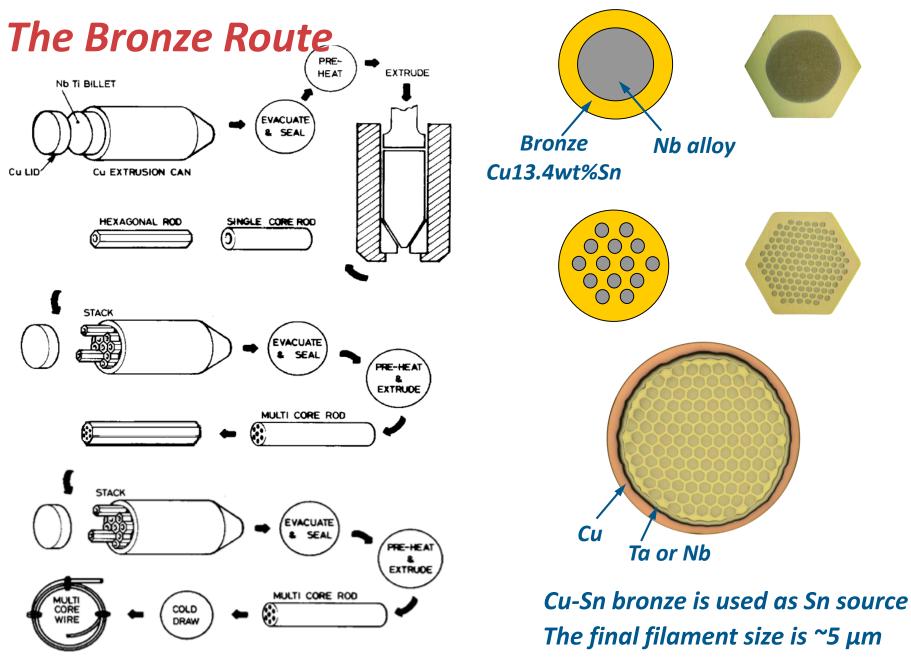
Ta substitutes both Nb and Sn

M. Suenaga et al., JAP 59 (1986) 840 S.M. Heald et al., Sci. Rep. <u>8</u> (2018) 4798

Industrial fabrication of Nb₃Sn wires

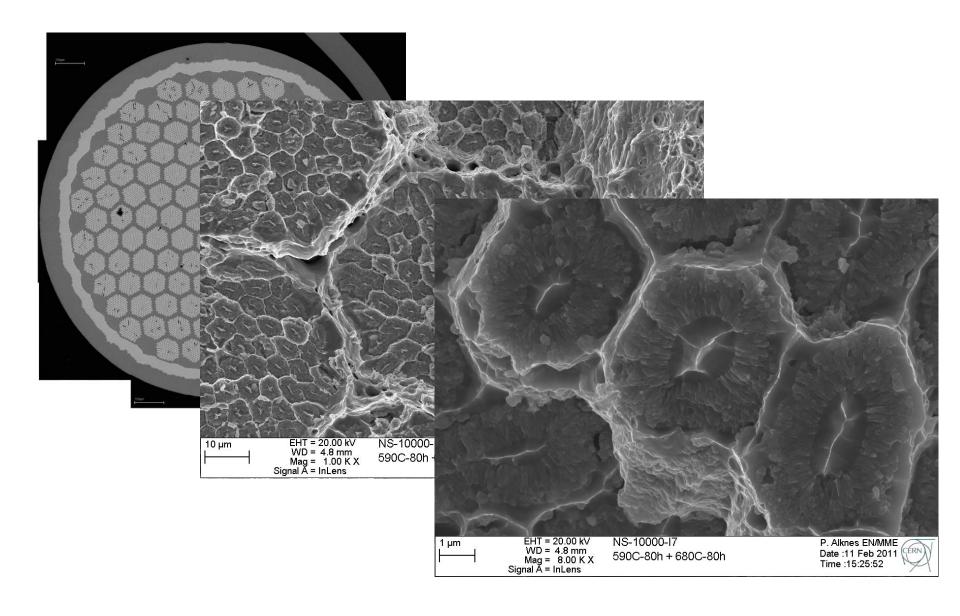
Three technologies have been developed at industrial scale



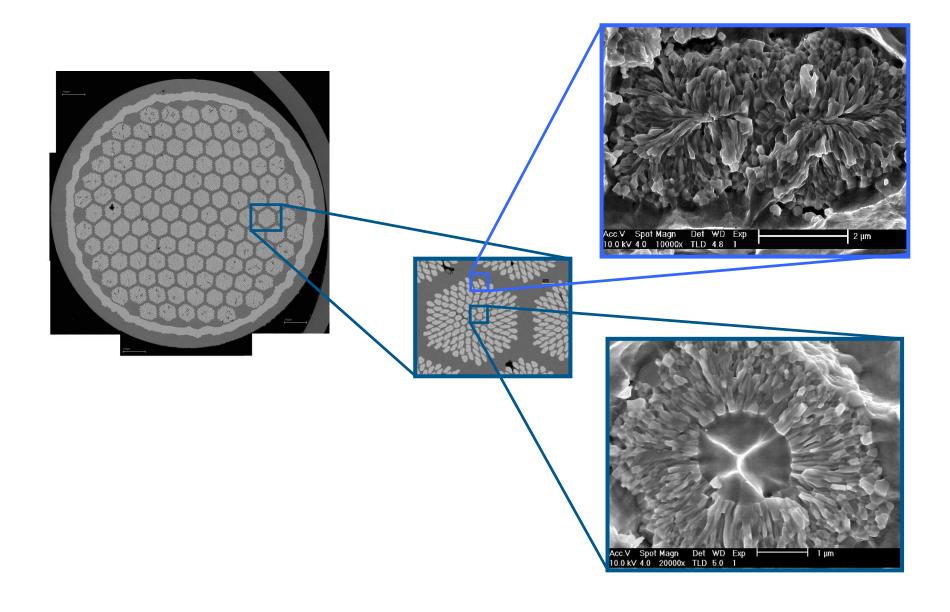


Wires are then reacted at ~650°C for >100 hours to form Nb₃Sn

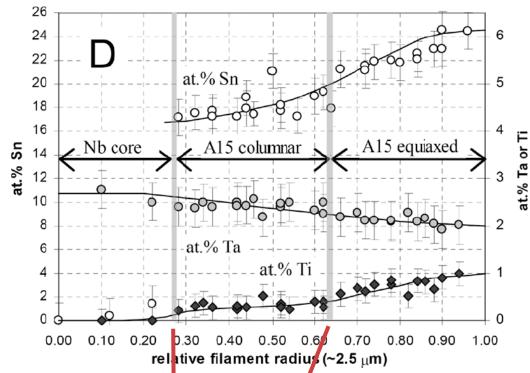
Bronze Route Nb₃Sn wires, after reaction

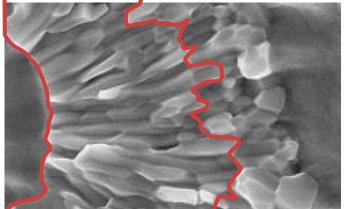


Bronze Route Nb₃Sn wires, after reaction



Sn gradient over the filament radius: Bronze Route



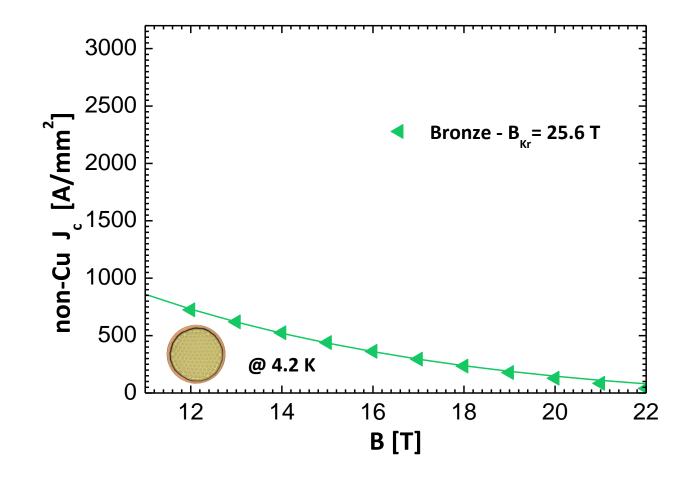


Correlation between Sn content and grain morphology Equiaxed grains: 21-25 at.% Sn Columnar grains: 18-21 at.%

Equiaxed grain size ~150 nm Columnar grain size up to 400 nm

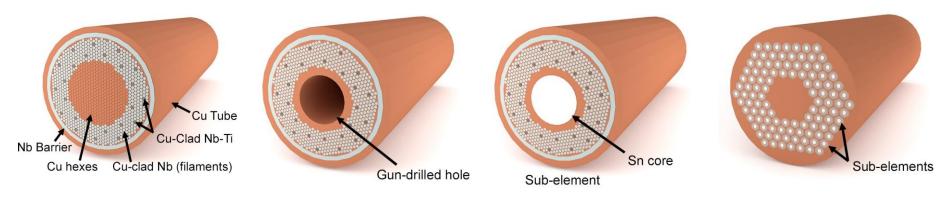
V. Abächerli et al., IEEE TASC <u>15</u> (2005) 3482

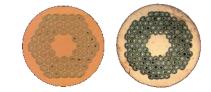
Critical current density vs. magnetic field Best performance achieved so far in industrial wires



V. Abächerli et al., IEEE TASC <u>17</u> (2007) 2564

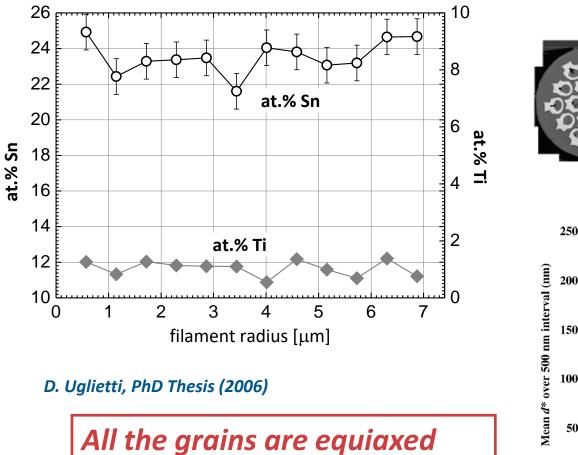
The Internal Sn diffusion process



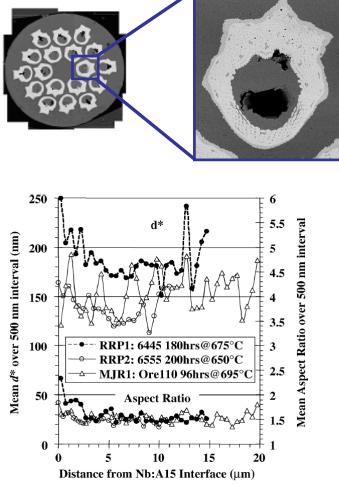


- A Sn rod is inserted in the subelement core
- After the insertion of Sn, only cold deformations are possible
- Subelement size ranges between 20 and 100 μm
- A long-duration multistep reaction schedule is required to form Nb₃Sn
 Pictures from C. Sanabria, PhD Thesis, FSU

Sn gradient over the filament radius: Internal Sn

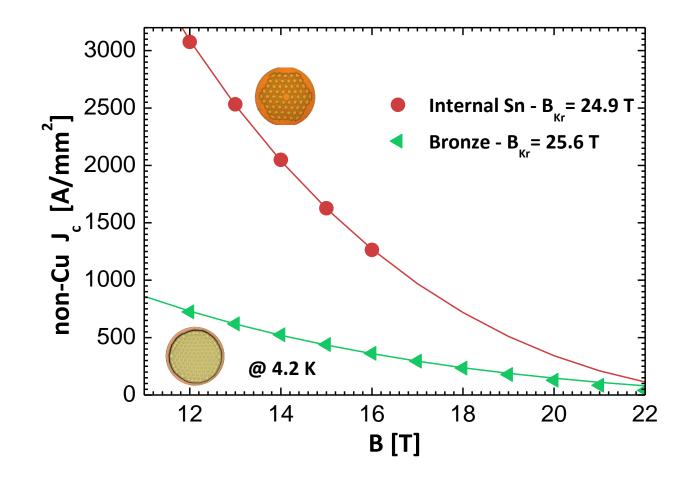


and almost stoichiometric !!



P. J. Lee and D. Larbalestier, IEEE Trans. Appl. Supercond. 15 (2005) 3474

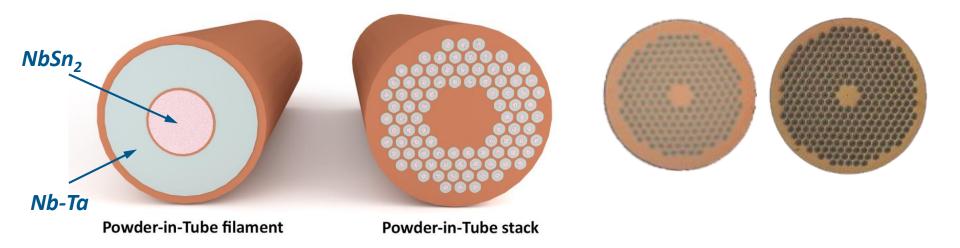
Critical current density vs. magnetic field Best performance achieved so far in industrial wires



J. Parrell et al., AIP Conf. Proc. <u>711</u> (2004) 369

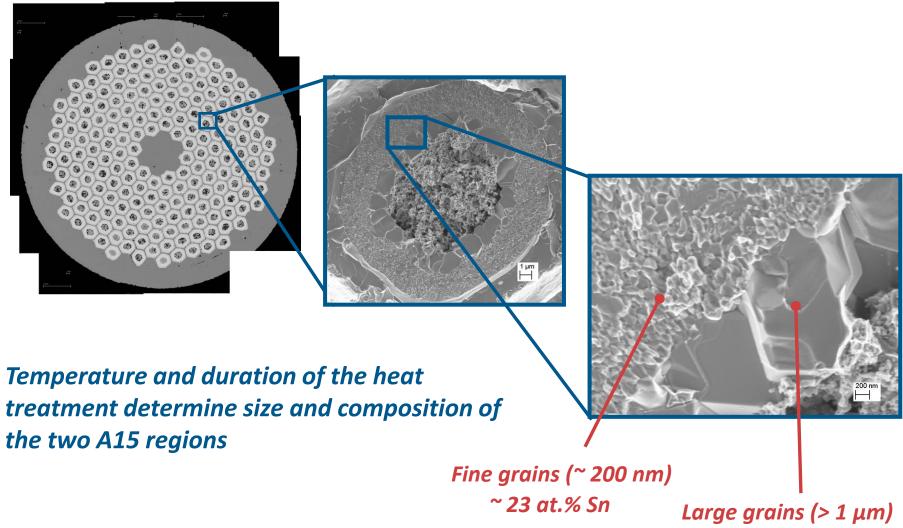
V. Abächerli et al., IEEE TASC <u>17</u> (2007) 2564

The Powder-In-Tube method



- NbSn₂ and Sn powders are used as Sn source
- Subelement size ranges between 20 and 100 μm
- A long-duration multistep reaction schedule is required to form Nb₃Sn

Formation and Microstructure of the A15 phases (1)



~ 25 at.% Sn

Formation and Microstructure of the A15 phases (2)

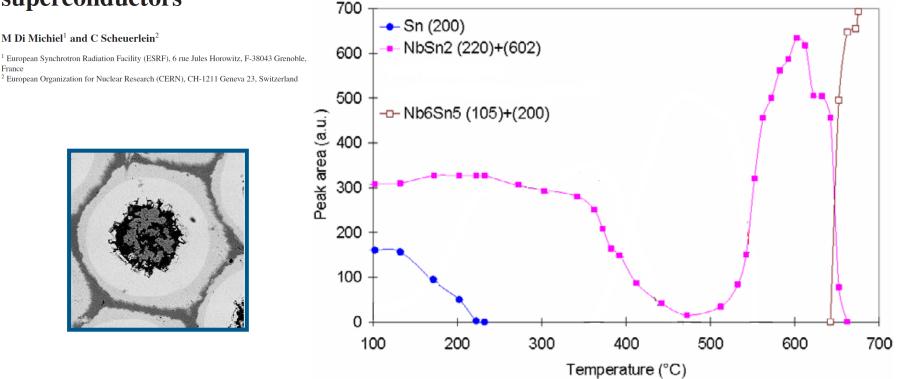
IOP PUBLISHING

SUPERCONDUCTOR SCIENCE AND TECHNOLOGY doi:10.1088/0953-2048/20/10/L01

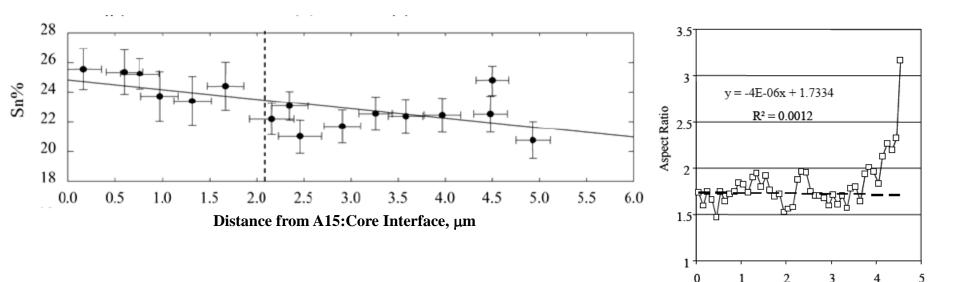
RAPID COMMUNICATION

Supercond. Sci. Technol. 20 (2007) L55-L58

Phase transformations during the reaction heat treatment of powder-in-tube Nb₃Sn superconductors

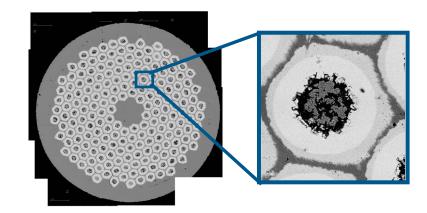


Sn gradient over the filament radius: PIT



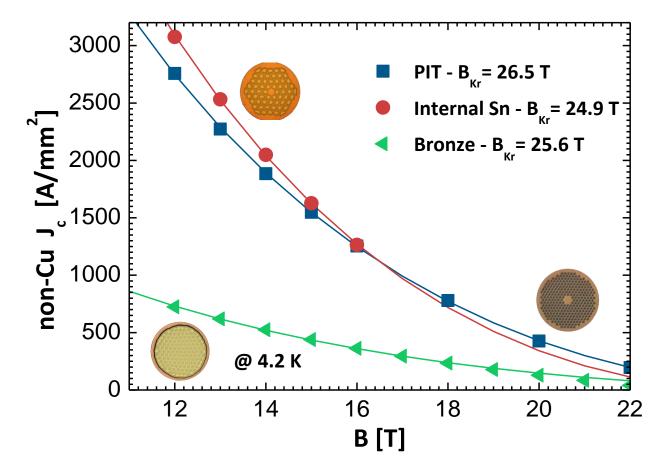
Distance from A15: Core Interface, µm

- Sn content decreases linearly along the filament radius
- Both fine and large grains are (almost) equiaxed



C.D. Hawes et al., Supercond. Sci. Technol. 19 (2006) 27

Critical current density vs. magnetic field Best performance achieved so far in industrial wires



T. Boutboul et al., IEEE TASC <u>19</u> (2009) 2564 J. Parrell et al., AIP Conf. Proc. <u>711</u> (2004) 369 V. Abächerli et al., IEEE TASC <u>17</u> (2007) 2564

Bronze Route vs. Internal Sn vs. PIT

Technology	Filament size	non-Cu J _c (12T,4.2K)	
Bronze Route	1-5 μm	750 A/mm²	Fine filaments \Rightarrow low hysteretic losses Bronze matrix \Rightarrow high mechanical strength Low Sn content \Rightarrow columnar grains, low J_c
Internal Sn	20-100 μm	3'200 A/mm ²	High Sn content + Fine grains \Rightarrow very high J _c Large filaments \Rightarrow high hysteretic losses
Powder-In- Tube	20-100 μm	2'700 A/mm ²	Fine grain region \Rightarrow high J _c Large grain region \Rightarrow very low J _c Large filaments \Rightarrow high hysteretic losses

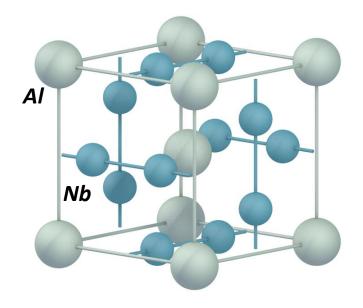
What we need:

Small grain size & high grain boundary density to get high pinning and thus high J_c High Sn content & appropriate Ta/Ti doping to get high B_{c2} and thus high in-field J_c

Another (almost) industrial A15 conductor: Nb₃Al

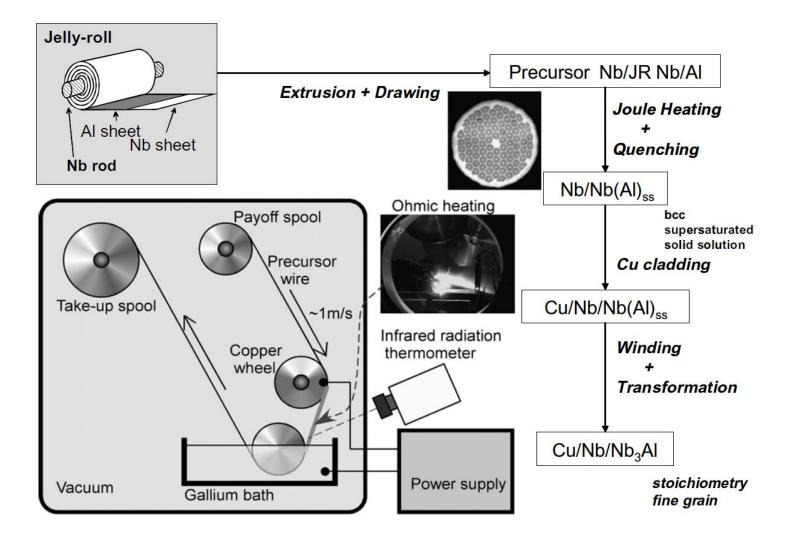
	<i>T_c</i> [K]	<i>B_{c2}</i> [T]
Nb ₃ Al	18.8	33

- Higher B_{c2} compared to Nb₃Sn
- Stoichiometric Nb₃Al cannot be formed by Al diffusion in Nb, with reaction @ 700°C



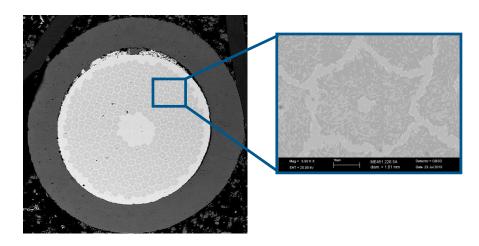
- Wire are fabricated by rapid-heating, quenching and transformation annealing (RHQT)
- The RHQT process enables the formation of stoichiometric Nb₃Al via a metastable bcc supersaturated-solid-solution of Nb and Al

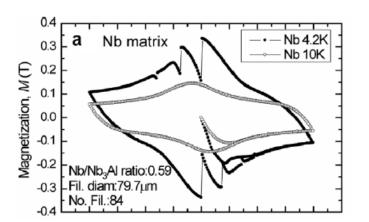
Nb₃Al wires: the RHQT process



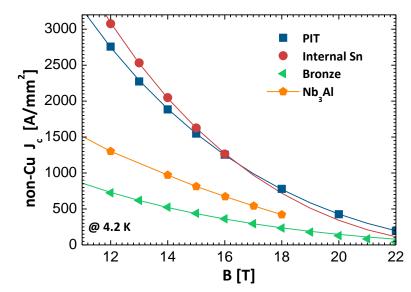
T. Takeuchi et al., Cryogenics 48 (2008) 371

Nb₃Al wires: cross section, filament layout & J_c





Coupling among filaments due to the Nb matrix



- J_c is lower compared to PIT and Internal Sn Nb₃Sn wires
- The advantage of Nb₃Al is the low sensitivity to applied strain

Bibliography

Rogalla & Kes 100 Years of Superconductivity Chapter 3 Section 7 Chapter 11 Section 2 (NbTi) Section 3 (Nb₃Sn)

Poole, Farach, Creswick, Prozorov Superconductivity Chapter 3

Papers cited in the slides